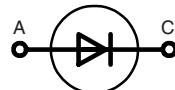


# HiPerFRED™ Epitaxial Diode with soft recovery

**I<sub>FAVM</sub>** = 6 A  
**V<sub>RRM</sub>** = 600 V  
**t<sub>rr</sub>** = 20 ns

V <sub>RSM</sub> V	V <sub>RRM</sub> V	Type	Marking on product
600	600	DSEP 6-06AS	6P060AS



TO-252AA (DPAK)



Symbol	Conditions	Maximum Ratings			Features
I <sub>FRMS</sub>	T <sub>VJ</sub> = T <sub>VJM</sub>	26	A		• Planar passivated chips
I <sub>FAVM</sub> ①	T <sub>C</sub> = 152°C; rectangular, d = 0.5	6	A		• Very short recovery time
I <sub>FRM</sub>	t <sub>p</sub> < 10 µs; rep. rating, pulse width limited by T <sub>VJM</sub>	12	A		• Extremely low switching losses
I <sub>FSM</sub>	T <sub>VJ</sub> = 45°C; t = 10 ms	(50 Hz), sine	40		• Low I <sub>RM</sub> -values
A					• Soft recovery behaviour
E <sub>AS</sub>	T <sub>VJ</sub> = 25°C; non-repetitive I <sub>AS</sub> = 0.8 A; L = 180 µH	0.1	mJ		
I <sub>AR</sub>	V <sub>A</sub> = 1.5 · V <sub>R</sub> typ.; f = 10 kHz; repetitive	0.1	A		
T <sub>VJ</sub>		-40...+175	°C		
T <sub>VJM</sub>		175	°C		
T <sub>stg</sub>		-40...+150	°C		
P <sub>tot</sub>	T <sub>C</sub> = 25°C	55	W		
Weight	typ.	0.3	g		

Symbol	Conditions	Characteristic Values		
		typ.	max.	
I <sub>R</sub>	T <sub>VJ</sub> = 25°C V <sub>R</sub> = V <sub>RRM</sub> T <sub>VJ</sub> = 150°C V <sub>R</sub> = V <sub>RRM</sub>	50	µA	
		0.2	mA	
V <sub>F</sub>	I <sub>F</sub> = 6 A; T <sub>VJ</sub> = 150°C T <sub>VJ</sub> = 25°C	1.33	V	
		2.02	V	
R <sub>thJC</sub>		2.8	K/W	
t <sub>rr</sub>	I <sub>F</sub> = 1 A; -di/dt = 200 A/µs; V <sub>R</sub> = 30 V; T <sub>VJ</sub> = 25°C	20	tbd	ns
I <sub>RM</sub>	V <sub>R</sub> = 100 V; I <sub>F</sub> = 10 A; -di <sub>F</sub> /dt = 100 A/µs T <sub>VJ</sub> = 100°C	3.5	4.4	A

① I<sub>FAVM</sub> rating includes reverse blocking losses  
at T<sub>VJM</sub>, V<sub>R</sub> = 0.6 V<sub>RRM</sub>, duty cycle d = 0.5

Data according to IEC 60747

## Applications

- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

## Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses
- Operating at lower temperature or space saving by reduced cooling

Dimensions see pages D4 - 85-86

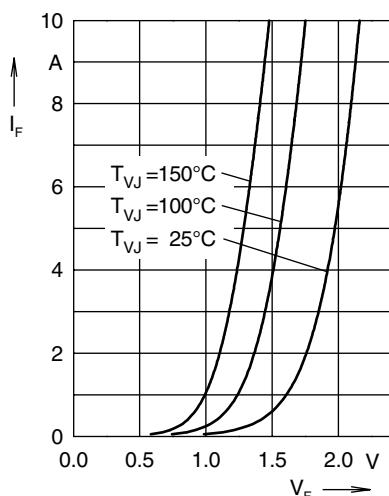


Fig. 1 Forward current  $I_F$  versus  $V_F$

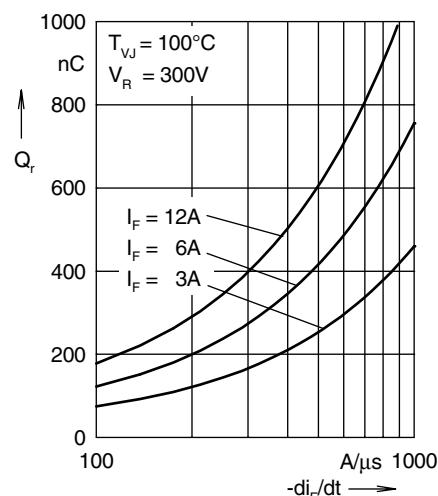


Fig. 2 Reverse recovery charge  $Q_r$  versus  $-di_F/dt$

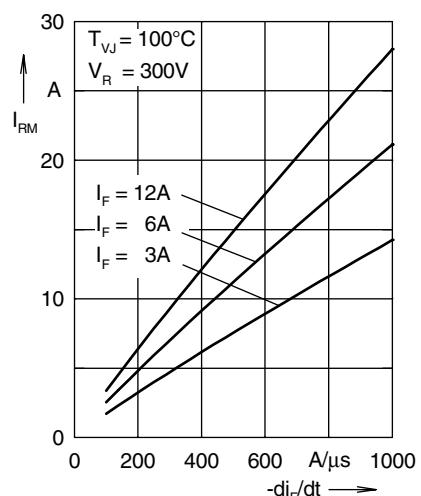


Fig. 3 Peak reverse current  $I_{RM}$  versus  $-di_F/dt$

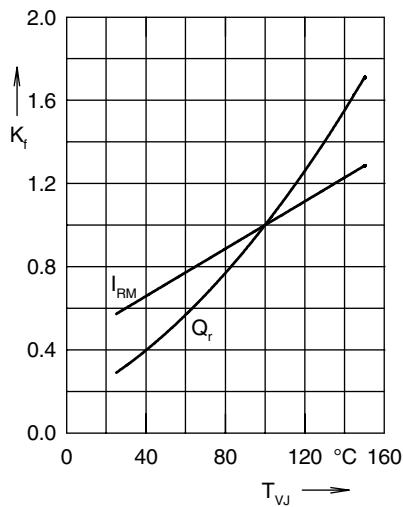


Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$

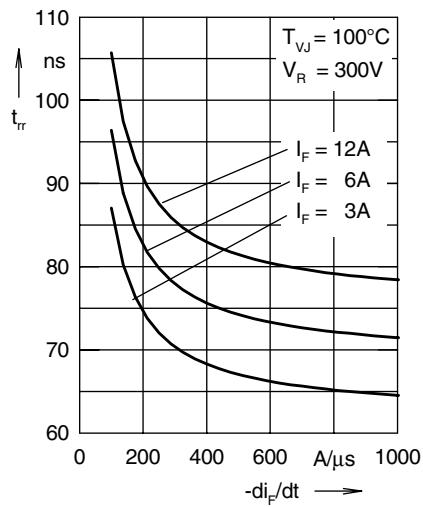


Fig. 5 Recovery time  $t_{rr}$  versus  $-di_F/dt$

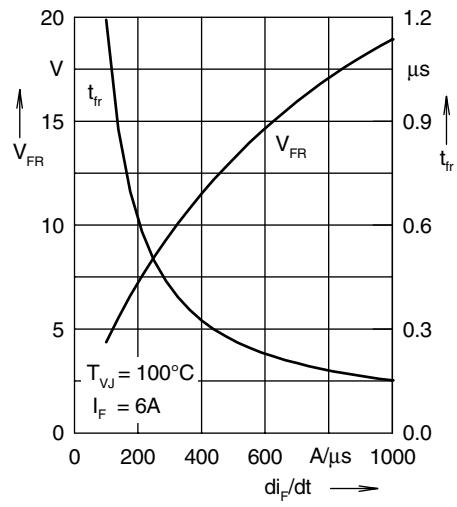


Fig. 6 Peak forward voltage  $V_{FR} + t_{fr}$  versus  $di_F/dt$

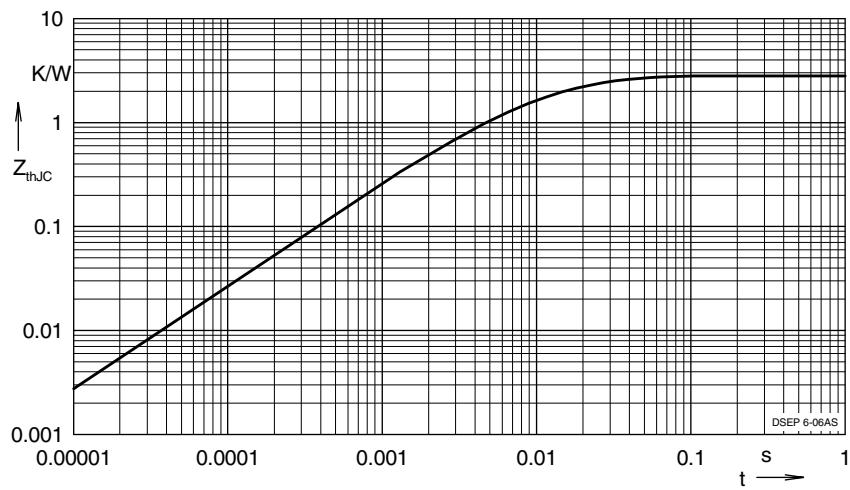


Fig. 7 Transient thermal resistance junction to case

NOTE: Fig. 2 to Fig. 6 shows typical values